IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Jiunn-Ren Hwang

Examiner: Ruggles, John S

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Anseime Chen

I-Heiung Huang

Filing Date: 05/10/2001

Art Unit: 1756

Serial No.:

09/851,580

Docket No.: NAUP0292USA

10 Title: METHOD OF FORMING STORAGE NODES IN A DRAM

To:

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

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Request for Continued Examination (RCE) in Subject:

response to the final office action dated

03/11/2003 and the advisory action dated

20 06/02/2003

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Dear Sir/Madam:

INTRODUCTORY COMMENTS

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In response to the Final Office Action and the Advisory Action noted above, the above-identified application is to be amended as indicated in the following sections.

Consideration of all amendments is politely requested.

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